

TECHNICAL DATA DATA SHEET 4621, REV.-

HERMETIC POWER SCHOTTKY RECTIFIER

(SINGLE / DUAL)

DESCRIPTION: A 30 VOLT, 30 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC LCC-3P PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ T_C = 25 °C UNLESS OTHERWISE SPECIFIED.

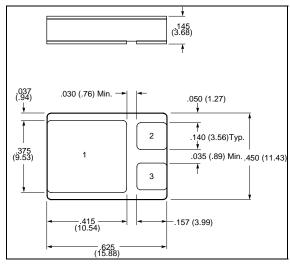
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	30	Volts
MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ T_c =100 $^{\circ}$ C) (Single)	Io	30	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t = 8.3ms, Sine)	I _{FSM}	200	Amps
MAXIMUM JUNCTION CAPACITANCE (V _r =5V)	C _T	2200	pF
MAXIMUM THERMAL RESISTANCE	R _{eJC}	0.61	°C/W
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 150	°C

ELECTRICAL CHARACTERISTICS

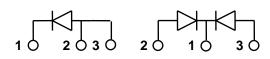
CHARACTERISTIC				
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I _f = 30 Amps)				
	$T_J = 25 ^{\circ}C$	V_{f}	0.58	Volts
	T _J = 125 °C		0.48	
MAXIMUM REVERSE CURRENT (Ir @ 30 V PIV)				
	$T_J = 25 ^{\circ}C$	l _r	4	mA
	T _J = 125 °C		200	

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MECHANICAL DIMENSIONS: IN Inches / mm





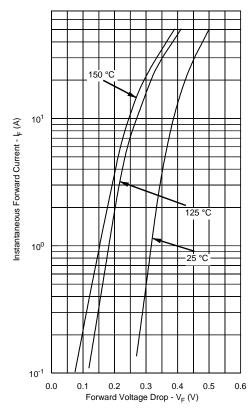


LCC-3P

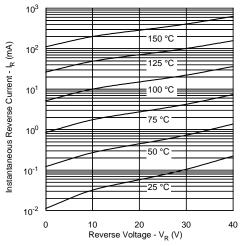
PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
COMMON CATHODE	COMMON CATHODE	ANODE 1	ANODE 2

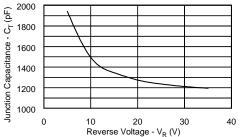




Typical Reverse Characteristics



Typical Junction Capacitance





TECHNICAL DATA

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